Electronic Supplementary Material (ESI) for CrystEngComm.

Supporting Information

Single crystal growth of layered metallic materials $TiTe_2$ based on a polytelluride flux method

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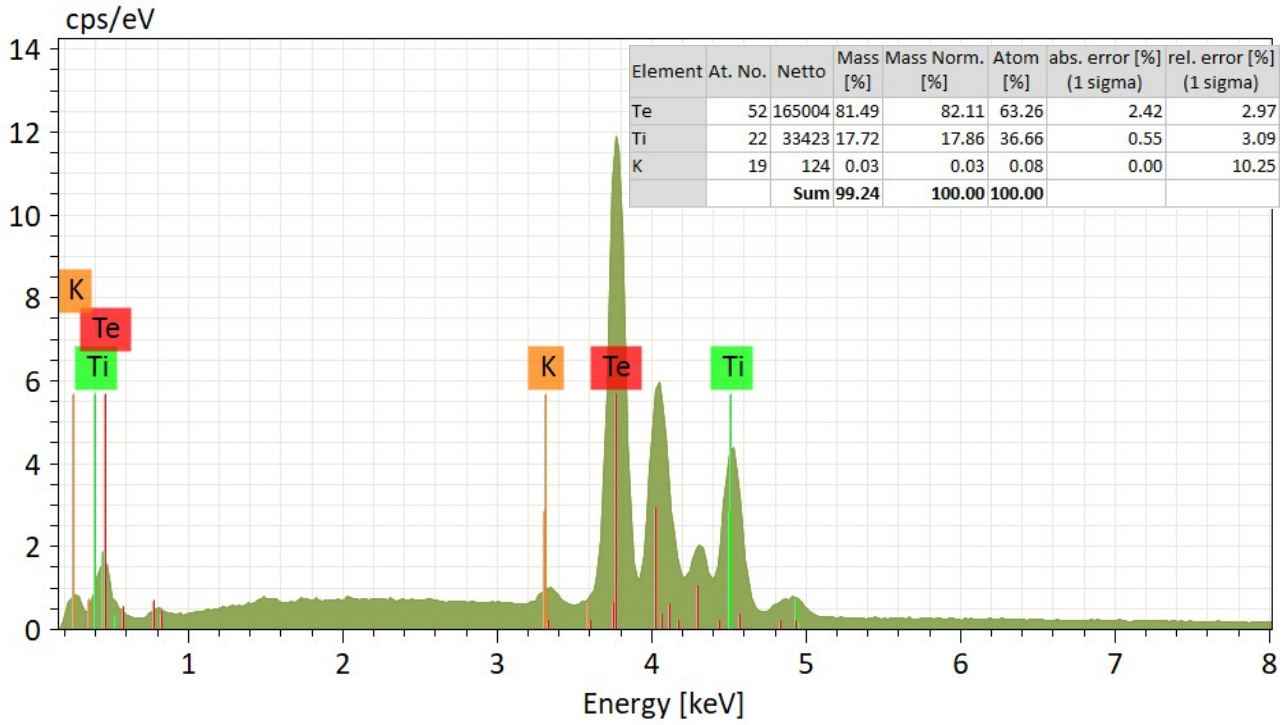

Fig. S1 The EDS spectrum of $TiTe_2$ from polytelluride flux in this work.

Table. S1 Work functions of the VB group TMDs reported in previous literatures.

Sample	Work function (eV)	methods	reference
VS_2	4.37	KPFM*1	[1]
1T-VSe_2 (bulk)	5.76	TCS*2	[2]
1T-VSe_2 (monolayer)	5.52	TCS	[3]
$NbSe_2$	5.9	UPS*3	[4]
NbS_2	4.75~4.9	UPS	[5]
1T-TaS_2	5.7	TCS	[6]

KPFM*1: Kelvin probe force microscopy

TCS*2: Target-current spectroscopy

UPS*3: Ultraviolet photoelectron spectroscopy

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